3SK186

Silicon N-Channel Dual Gate MOS FET

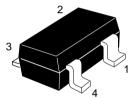
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Application

UHF TV tuner RF amplifier

Outline

MPAK-4



- 1. Source
- 2. Gate1
- 3. Gate2
- 4. Drain



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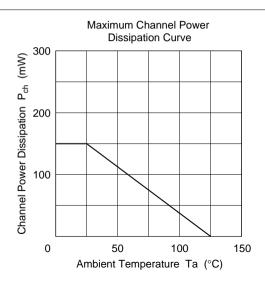
Absolute Maximum Ratings (Ta = 25°C)

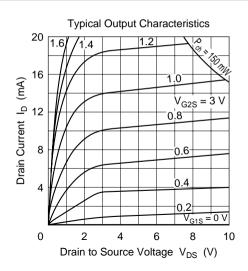
| Item | Symbol | Ratings | Unit |
|---------------------------|----------------|-------------|------|
| Drain to source voltage | V_{DS} | 12 | V |
| Gate 1 to source voltage | $V_{\sf G1S}$ | ±10 | V |
| Gate 2 to source voltage | V_{G2S} | ±10 | V |
| Drain current | I _D | 35 | mA |
| Channel power dissipation | Pch | 150 | mW |
| Channel temperature | Tch | 125 | °C |
| Storage temperature | Tstg | -55 to +125 | °C |

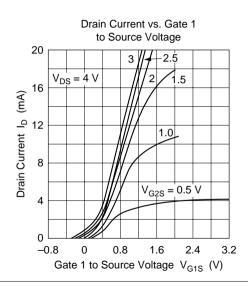
Electrical Characteristics ($Ta = 25^{\circ}C$)

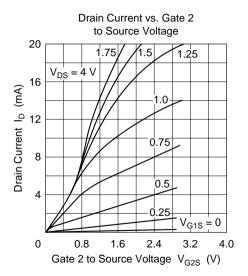
| Item | Symbol | Min | Тур | Max | Unit | Test conditions |
|------------------------------------|-----------------------|------|-------|------|------|--|
| Drain to source breakdown voltage | $V_{(BR)DSX}$ | 12 | _ | _ | V | $V_{G1S} = V_{G2S} = -5 \text{ V},$ $I_D = 200 \mu\text{A}$ |
| Gate 1 to source breakdown voltage | $V_{(BR)G1SS}$ | ±10 | _ | _ | V | $I_{G1} = \pm 10 \ \mu A, \ V_{G2S} = V_{DS} = 0$ |
| Gate 2 to source breakdown voltage | $V_{(BR)\;G2SS}$ | ±10 | _ | _ | V | $I_{G2} = \pm 10 \ \mu A, \ V_{G1S} = V_{DS} = 0$ |
| Gate 1 cutoff current | I _{G1SS} | _ | _ | ±100 | nA | $V_{G1S} = \pm 8 \text{ V}, V_{G2S} = V_{DS} = 0$ |
| Gate 2 cutoff current | I _{G2SS} | _ | _ | ±100 | nA | $V_{G2S} = \pm 8 \text{ V}, V_{G1S} = V_{DS} = 0$ |
| Gate 1 to source cutoff voltage | $V_{\text{G1S(off)}}$ | +0.5 | _ | -0.8 | V | $V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{V},$ $I_{D} = 100 \mu\text{A}$ |
| Gate 2 to source cutoff voltage | $V_{\text{G2S(off)}}$ | +0.5 | _ | -0.8 | V | $V_{DS} = 6 \text{ V}, V_{G1S} = 3 \text{V},$ $I_{D} = 100 \mu\text{A}$ |
| Drain current | I _{DSS} | 0 | _ | 4 | mA | $V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{V}, V_{G1S} = 0$ |
| Forward transfer admittance | $ y_{fs} $ | 15 | _ | _ | mS | $V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{V},$ $I_{D} = 10 \text{ mA}, f = 1 \text{ kHz}$ |
| Input capacitance | Ciss | _ | 1.7 | 2.2 | pF | $V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{V},$ $I_{D} = 10 \text{ mA}, f = 1 \text{ MHz}$ |
| Output capacitance | Coss | _ | 1.0 | 1.4 | pF | - |
| Reverse transfer capacitance | Crss | _ | 0.017 | 0.03 | pF | - |
| Power gain | PG | 16 | 19 | _ | dB | $V_{DS} = 4 \text{ V}, V_{G2S} = 3 \text{V},$ $I_{D} = 10 \text{ mA}, f = 900 \text{ MHz}$ |
| Noise figure | NF | _ | 3.0 | 4.5 | dB | |

Note: Marking is "FI-".

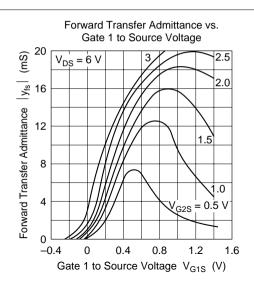


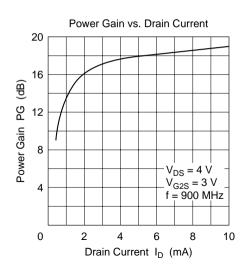


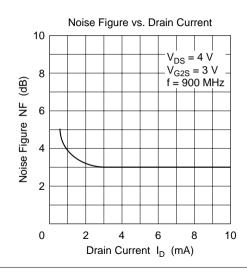




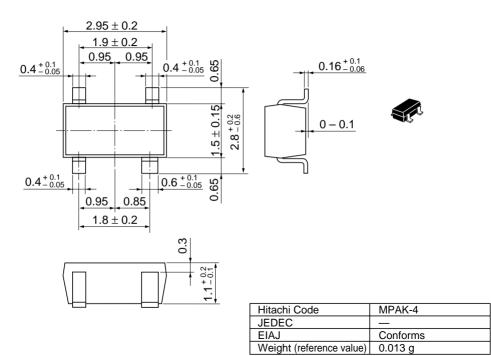
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Unit: mm



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